

July 2007

## EGP30A - EGP30K

# 3.0 Ampere Glass Passivated High Efficiency Rectifiers

## **Features**

- · Glass passivated cavity-free junction
- · High surge current capability
- · Low leakage current
- · Superfast recovery time for high efficiency
- · Low forward voltage, high current capability



DO-201AD Glass case COLOR BAND DENOTES CATHODE

Absolute Maximum Ratings\* T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
I <sub>O</sub>	Average Rectified Current .375 " lead length @ TL = 55°C	3.0	А
İf(surge)	Peak Forward Surge Current 8.3 ms single half-sine-wave Superimposed on rated load (JEDEC method)	125	Α
P <sub>D</sub>	Total Device Dissipation	6.25	W
	Derate above 25°C	50	mW°C
Reja	Thermal Resistance, Junction to Ambient	20	°C/W
Rejl	Thermal Resistance, Junction to Lead	8.5	°C/W
T <sub>J</sub> , T <sub>STG</sub>	Junction and Storage Temperature Range	-65 ~ 150	°C

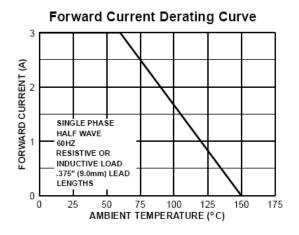
<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

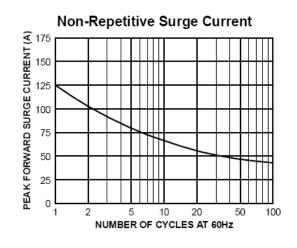
## Electrical Characteristics\* T<sub>a</sub> = 25°C unless otherwise noted

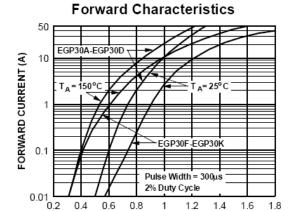
	Device								
Parameter	30A	30B	30C	30D	30F	30G	30J	30K	Units
Peak Repetitive Reverse Voltage	50	100	150	200	300	400	600	800	V
Maximum RMS Voltage	35	70	105	140	210	280	420	560	V
DC Reverse Voltage (Rated VR)	50	100	150	200	300	400	600	800	V
Maximum Reverse Current @ rated VR TA = 25°C TA = 125°C	5.0 100								μ <b>Α</b> μ <b>Α</b>
Maximum Reverse Recovery Time IF = 0.5 A, IR = 1.0 A, Irr = 0.25 A	50 75							nS	
Maximum Forward Voltage @ 3.0 A		0.95				1.25		.7	V
Typical Junction Capacitance VR = 4.0 V, f = 1.0 MHz		95 75						pF	

<sup>\*</sup> Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%

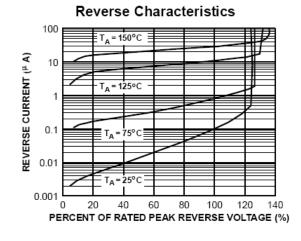
## **Typical Performance Characteristics**

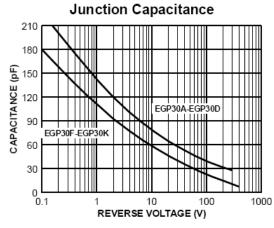




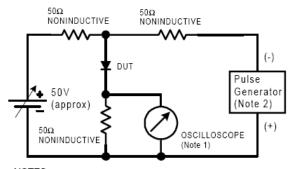


FORWARD VOLTAGE (V)



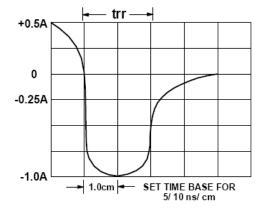


## **Reverse Recovery Time Characterstic and Test Circuit Diagram**



#### NOTES

- 1. Rise time = 7.0 ns max; Input impedance = 1.0 megaohm 22 pf.
- 2. Rise time = 10 ns max; Source impedance = 50 ohms.







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